

### 3-PHASE BRIDGE DRIVER

#### Features

- Floating channel designed for bootstrap operation  
Fully operational to +600V or +1200V  
Tolerant to negative transient voltage  
dV/dt immune
- Gate drive supply range from 10V/12V to 20V DC and up to 25V for transient
- Undervoltage lockout for all channels
- Over-current shut down turns off all six drivers
- Independent 3 half-bridge drivers
- Matched propagation delay for all channels
- 2.5V logic compatible
- Outputs out of phase with inputs

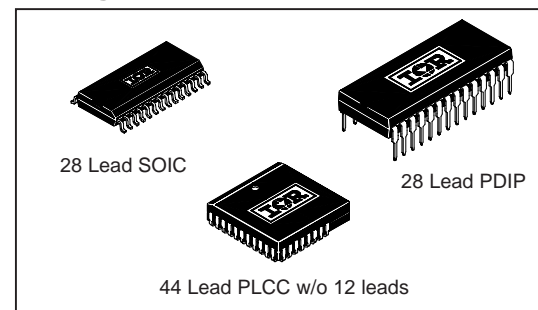
#### Description

The IR21333/IR2135/IR2233/IR2235 are high voltage, high speed power MOSFET and IGBT driver with three independent high side and low side referenced output channels for 3-phase applications. Proprietary HVIC technology enables ruggedized monolithic construction. Logic inputs are compatible with CMOS or LSTTL outputs, down to 2.5V logic. An independent operational amplifier provides an analog feedback of bridge current via an external current sense resistor. A current trip function which terminates all six outputs can also be derived from this resistor. A shutdown function is available to terminate all six outputs. An open drain  $\overline{\text{FAULT}}$  signal is provided to indicate that an over-current or undervoltage shutdown has occurred. Fault conditions are cleared with the  $\overline{\text{FLT-CLR}}$  lead. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction.

#### Product Summary

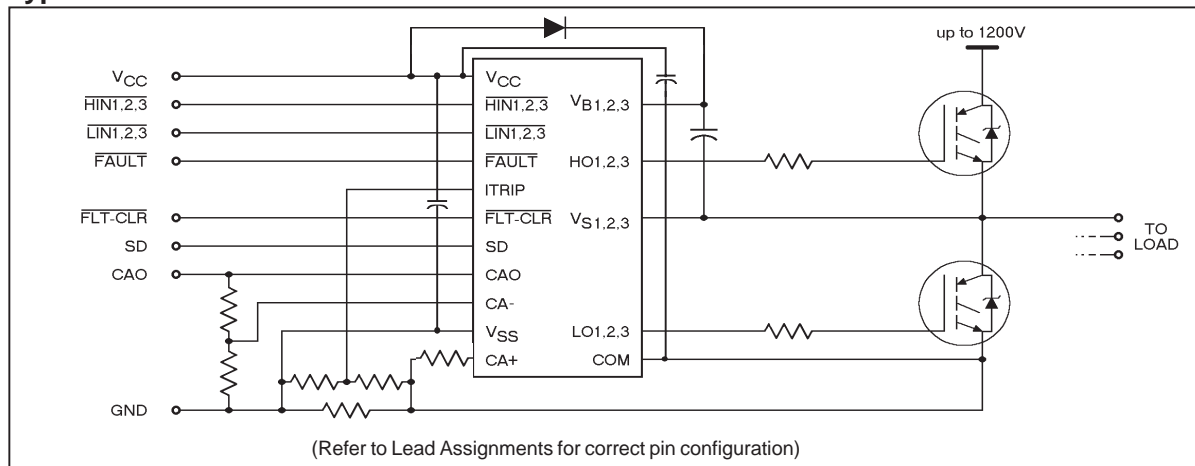
$V_{\text{OFFSET}}$	600V or 1200V max.
$I_{\text{O}+/-}$	200 mA / 420 mA
$V_{\text{OUT}}$	10 - 20V or 12 - 20V
$t_{\text{on/off (typ.)}}$	700 ns
Deadtime (typ.)	200 ns

#### Packages



Propagation delays are matched to simplify use in high frequency applications. The floating channels can be used to drive N-channel power MOSFETs or IGBTs in the high side configuration which operates up to 600 volts or 1200 volts.

#### Typical Connection



# IR2133/IR2135/IR2233/IR2235 (J)(S)

## Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units	
V <sub>B1,2,3</sub>	High side floating supply voltage	(IR2133/IR2135)	-0.3	625	V
		(IR2233/IR2235)	-0.3	1225	
V <sub>S1,2,3</sub>	High side floating supply offset voltage	V <sub>B1,2,3</sub> - 25	V <sub>B1,2,3</sub> + 0.3		
V <sub>HO1,2,3</sub>	High side floating output voltage	V <sub>S1,2,3</sub> - 0.3	V <sub>B1,2,3</sub> + 0.3		
V <sub>CC</sub>	Fixed supply voltage	-0.3	25		
V <sub>SS</sub>	Logic ground	V <sub>CC</sub> - 25	V <sub>CC</sub> + 0.3		
V <sub>LO1,2,3</sub>	Low side output voltage	-0.3	V <sub>CC</sub> + 0.3		
V <sub>IN</sub>	Logic input voltage (HIN, LIN, ITRIP, SD & FLT-CLR)	V <sub>SS</sub> - 0.3	V <sub>SS</sub> + 15		
V <sub>IN,AMP</sub>	Op amp input voltage (CA+ & CA-)	V <sub>SS</sub> - 0.3	V <sub>CC</sub> + 0.3		
V <sub>OUT,AMP</sub>	Op amp output voltage (CAO)	V <sub>SS</sub> - 0.3	V <sub>CC</sub> + 0.3		
V <sub>FLT</sub>	FAULT output voltage	V <sub>SS</sub> - 0.3	V <sub>CC</sub> + 0.3		
dVs/dt	Allowable offset supply voltage transient	---	50	V/ns	
P <sub>D</sub>	Package power dissipation @ T <sub>A</sub> ≤ 25°C	(28 Lead PDIP)	---	1.5	W
		(28 Lead SOIC)	---	1.6	
		(44 lead PLCC)	---	2.0	
R <sub>th,JA</sub>	Thermal resistance, junction to ambient	(28 Lead PDIP)	---	83	°C/W
		(28 Lead SOIC)	---	78	
		(44 lead PLCC)	---	63	
T <sub>J</sub>	Junction temperature	---	125	°C	
T <sub>S</sub>	Storage temperature	-55	150		
T <sub>L</sub>	Lead temperature (soldering, 10 seconds)	---	300		

## Recommended Operating Conditions

The input/output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. All voltage parameters are absolute voltages referenced to COM. The VS offset rating is tested with all supplies biased at 15V differential.

Symbol	Parameter Definition	Min.	Max.	Units	
V <sub>B1,2,3</sub>	High side floating supply voltage	V <sub>S1,2,3</sub> + 10/12	V <sub>S1,2,3</sub> + 20	V	
V <sub>S1,2,3</sub>	High side floating supply offset voltage	(IR2133/IR2135)	Note 1		600
		(IR2233/IR2235)	Note 1		1200
V <sub>HO1,2,3</sub>	High side floating output voltage	V <sub>S1,2,3</sub>	V <sub>B1,2,3</sub>		
V <sub>CC</sub>	Fixed supply voltage	10 or 12	20		
V <sub>SS</sub>	Low side driver return	-5	5		
V <sub>LO1,2,3</sub>	Low side output voltage	0	V <sub>CC</sub>		
V <sub>IN</sub>	Logic input voltage (HIN, LIN, ITRIP, SD & FLT-CLR)	V <sub>SS</sub>	V <sub>SS</sub> + 5		
V <sub>IN,AMP</sub>	Op amp input voltage (CA+ & CA-)	V <sub>SS</sub>	V <sub>SS</sub> + 5		
V <sub>OUT,AMP</sub>	Op amp output voltage (CAO)	V <sub>SS</sub>	V <sub>SS</sub> + 5		
V <sub>FLT</sub>	FAULT output voltage	V <sub>SS</sub>	V <sub>CC</sub>		

**Note 1:** Logic operational for VS of COM - 5V to COM + 600V/1200V. Logic state held for VS of COM -5V to COM -VBS.

**Note 2:** All input pins, op amp input and output pins are internally clamped with a 5.2V zener diode.

### Dynamic Electrical Characteristics

$V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS1,2,3}$ ) = 15V,  $V_{S1,2,3}$  =  $V_{SS}$ ,  $T_A$  = 25°C and  $C_L$  = 1000 pF unless otherwise specified.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
$t_{on}$	Turn-on propagation delay		700		ns	$V_{IN} = 0$ & 5V $V_{S1,2,3} = 0$ to 600V or 1200V
$t_{off}$	Turn-off propagation delay		700			
$t_r$	Turn-on rise time		75			
$t_f$	Turn-off fall time		35			
$t_{sd}$	SD to output shutdown propagation delay		700			
$t_{itrip}$	ITRIP to output shutdown propagation delay		700			
$t_{bl}$	ITRIP blanking time		400			
$t_{flt}$	ITRIP to $\overline{FAULT}$ propagation delay		500			
$t_{fil,in}$	Input filter time ( $HIN$ , $LIN$ and SD)		310			
$t_{fltclr}$	FLT-CLR to $\overline{FAULT}$ clear time		650			
DT	Deadtime, LS turn-off to HS turn-on & HS turn-off to LS turn-on		200		V/ $\mu$ s	$V_{IN} = 0$ & 5V
SR+	Amplifier slew rate (positive)		15			
SR-	Amplifier slew rate (negative)		10			

NOTE: For high side PWM, HIN pulse width must be  $\geq 1\mu$  sec

### Static Electrical Characteristics

$V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS1,2,3}$ ) = 15V unless otherwise specified and  $T_A$  = 25°C. The  $V_{IN}$ ,  $V_{TH}$  and  $I_{IN}$  parameters are referenced to  $V_{SS}$  and are applicable to all six channels ( $HS_{1,2,3}$  &  $LS_{1,2,3}$ ). The  $V_O$  and  $I_O$  parameters are referenced to  $V_{SS}$  and  $V_{S1,2,3}$  and are applicable to the respective output leads:  $HO_{1,2,3}$  or  $LO_{1,2,3}$ .

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
$V_{IH}$	Logic "0" Input Voltage (OUT = LO)	2.2	—	—	V	
$V_{IL}$	Logic "1" Input Voltage (OUT = HI)	—	—	0.8		
$V_{FCLR,IH}$	Logic "0" Fault Clear Input Voltage	2.2	—	—		
$V_{FCLR,IL}$	Logic "1" Fault Clear Input Voltage	—	—	0.8		
$V_{SD,TH+}$	SD Input Positive Going Threshold		1.8			
$V_{SD,TH-}$	SD Input Negative Going Threshold		1.5			
$V_{IT,TH+}$	ITRIP Input Positive Going Threshold		485		mV	
$V_{IT,TH-}$	ITRIP Input Negative Going Threshold		400			
$V_{OH}$	High Level Output Voltage, $V_{BIAS} - V_O$	—	—	100		$V_{IN} = 0V$ , $I_O = 0A$
$V_{OL}$	Low Level Output Voltage, $V_O$	—	—	100		$V_{IN} = 5V$ , $I_O = 0A$
$I_{LK}$	Offset Supply Leakage Current (IR2133/IR2135) (IR2233/IR2235)	—	—	50	$\mu$ A	$V_{B1,2,3} = V_{S1,2,3} = 600V$
		—	—	50		$V_{B1,2,3} = V_{S1,2,3} = 1200V$
$I_{QBS}$	Quiescent $V_{BS}$ Supply Current		50		mA	$V_{IN} = 0V$ or 5V
$I_{QCC}$	Quiescent $V_{CC}$ Supply Current		4.0			
$I_{IN+}$	Logic "1" Input Bias Current (OUT = HI)		150		$\mu$ A	$V_{IN} = 0V$
$I_{IN-}$	Logic "0" Input Bias Current (OUT = LO)		80			$V_{IN} = 5V$
$I_{SD+}$	"High" Shutdown Bias Current		50			SD = 5V
$I_{SD-}$	"Low" Shutdown Bias Current	—	—	50	nA	SD = 0V
$I_{ITRIP+}$	"High" ITRIP Bias Current		50		$\mu$ A	ITRIP = 5V
$I_{ITRIP-}$	"Low" ITRIP Bias Current	—	—	50	nA	ITRIP = 0V

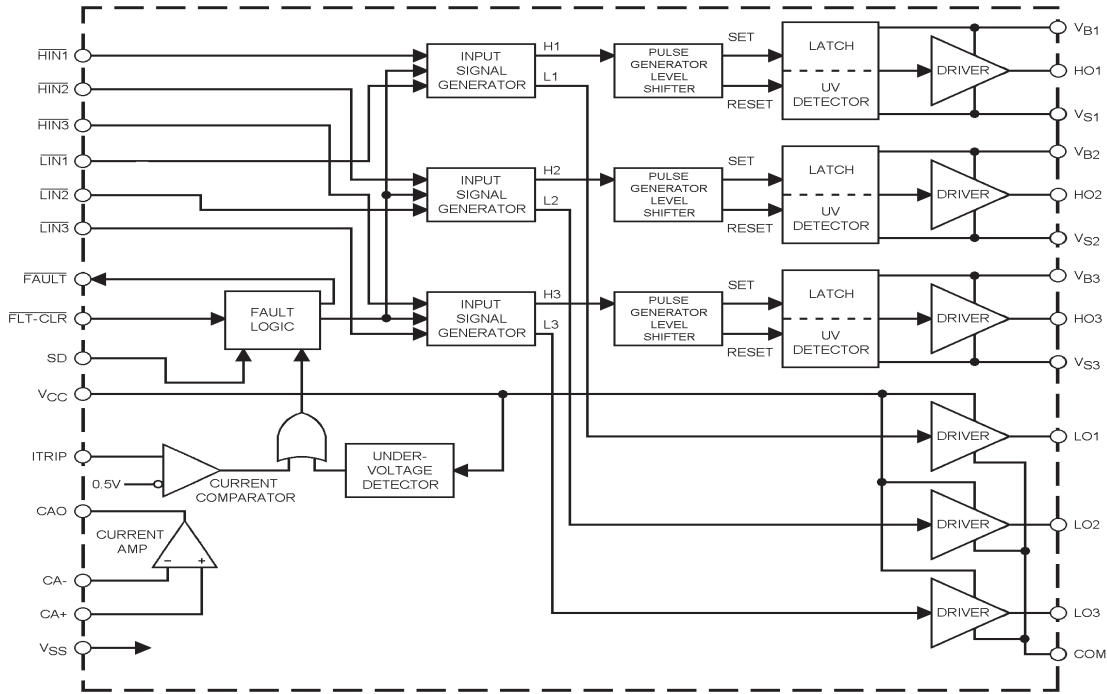
# IR2133/IR2135/IR2233/IR2235 (J)(S)

## Static Electrical Characteristics — Continued

$V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS1,2,3}$ ) = 15V and  $T_A$  = 25°C unless otherwise specified. The  $V_{IN}$ ,  $V_{TH}$  and  $I_{IN}$  parameters are referenced to  $V_{SS}$  and are applicable to all six channels (HS1,2,3 & LS1,2,3). The  $V_O$  and  $I_O$  parameters are referenced to  $V_{SS}$  and  $V_{S0,1,2,3}$  and are applicable to the respective output leads: HO or LO.

Symbol	Parameter Definition	Min.	Typ.	Max.	Units	Test Conditions
$I_{FLTCLR+}$	"High" Fault Clear Input Bias Current		150		$\mu A$	$\overline{FLT-CLR} = 0V$
$I_{FLTCLR-}$	"Low" Fault Clear Input Bias Current		80			$\overline{FLT-CLR} = 5V$
$V_{BSUV+}$	$V_{BS}$ Supply Undervoltage Positive Going Threshold (for IR2133/IR2233) (for IR2135/IR2235)		8.7 10.4		V	
$V_{BSUV-}$	$V_{BS}$ Supply Undervoltage Negative Going Threshold (for IR2133/IR2233) (for IR2135/IR2235)		8.3 9.4			
$V_{BSUVH}$	$V_{BS}$ Supply Undervoltage Lockout Hysteresis (for IR2133/IR2233) (for IR2135/IR2235)		0.4 1.0			
$V_{CCUV+}$	$V_{CC}$ Supply Undervoltage Positive Going Threshold (for IR2133/IR2233) (for IR2135/IR2235)		8.7 10.4			
$V_{CCUV-}$	$V_{CC}$ Supply Undervoltage Negative Going Threshold (for IR2133/IR2233) (for IR2135/IR2235)		8.3 9.4			
$V_{CCUVH}$	$V_{CC}$ Supply Undervoltage Lockout Hysteresis (for IR2133/IR2233) (for IR2135/IR2235)		0.4 1.0			
$R_{on,FLT}$	FAULT- Low On Resistance		60			$\Omega$
$I_{O+}$	Output High Short Circuit Pulsed Current	200	250	---	mA	$V_{OUT} = 0V, V_{IN} = 0V$ $PW \leq 10 \mu s$
$I_{O-}$	Output Low Short Circuit Pulsed Current	420	500	---		$V_{OUT} = 15V, V_{IN} = 5V$ $PW \leq 10 \mu s$
$V_{OS}$	Amplifier Input Offset Voltage	---	---	10	mV	$CA+ = 0.2V, CA- = CAO$
$I_{IN,AMP}$	Amplifier Input Bias Current	---	---	4	nA	$CA+ = CA- = 2.5V$
CMRR	Amplifier Common Mode Rejection Ratio		80		dB	$CA+ = 0.1V \& 5V, CA- = CAO$
PSRR	Amplifier Power Supply Rejection Ratio		80			$CA+ = 0.2V, CA- = CAO$ $V_{CC} = 10V \& 20V$
$V_{OH,Amp}$	Amplifier High Level Output Voltage		5.2		V	$CA+ = 1V, CA- = 0V$
$V_{OL,Amp}$	Amplifier Low Level Output Voltage	---	---	20	mV	$CA+ = 0V, CA- = 1V$
$I_{SRC,Amp}$	Amplifier Output Source Current		8.0		mA	$CA+ = 1V, CA- = 0V, CAO = 4V$
$I_{SNK,Amp}$	Amplifier Output Sink Current		1.0			$CA+ = 0V, CA- = 1V, CAO = 2V$
$I_{O+,Amp}$	Amplifier Output High Short Circuit Current		10			$CA+ = 5V, CA- = 0V, CAO = 0V$
$I_{O-,Amp}$	Amplifier Output Low Short Circuit Current		5.0			$CA+ = 0V, CA- = 5V, CAO = 5V$

**Functional Block Diagram**



**Lead Definitions**

Symbol	Lead Description
$\overline{\text{HIN1,2,3}}$	Logic inputs for high side gate driver outputs (HO1,2,3), out of phase.
$\overline{\text{LIN1,2,3}}$	Logic inputs for low side gate driver outputs (LO1,2,3), out of phase.
$\overline{\text{FAULT}}$	Indicates over-current or undervoltage lockout (low side) has occurred, negative logic.
Vcc	Logic and low side fixed supply.
ITRIP	Input for over-current shut down.
$\overline{\text{FLT-CLR}}$	Logic input for fault clear, negative logic.
SD	Logic input for shut down.
CAO	Output of current amplifier.
CA-	Negative input of current amplifier.
CA+	Positive input of current amplifier.
Vss	Logic ground.
COM	Low side return.
V <sub>B1,2,3</sub>	High side floating supplies.
HO1,2,3	High side gate drive outputs.
V <sub>S1,2,3</sub>	High side floating supply returns.
LO1,2,3	Low side gate drive outputs

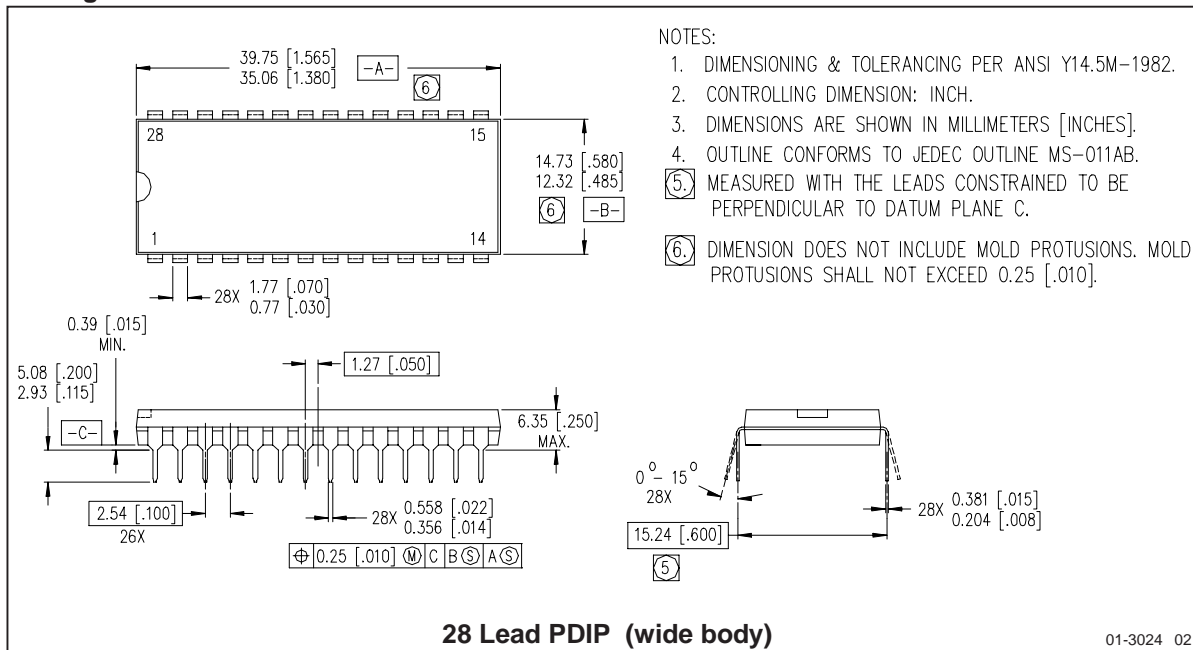
# IR2133/IR2135/IR2233/IR2235 (J)(S)



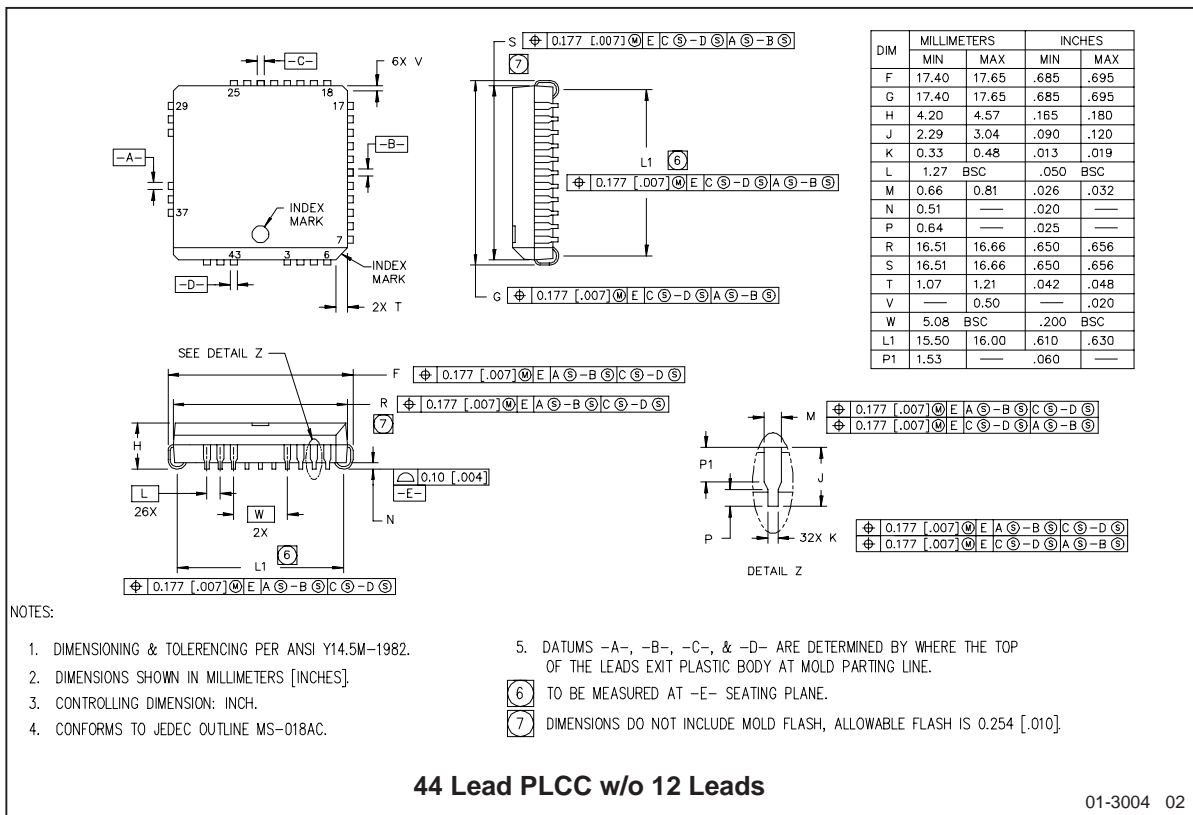
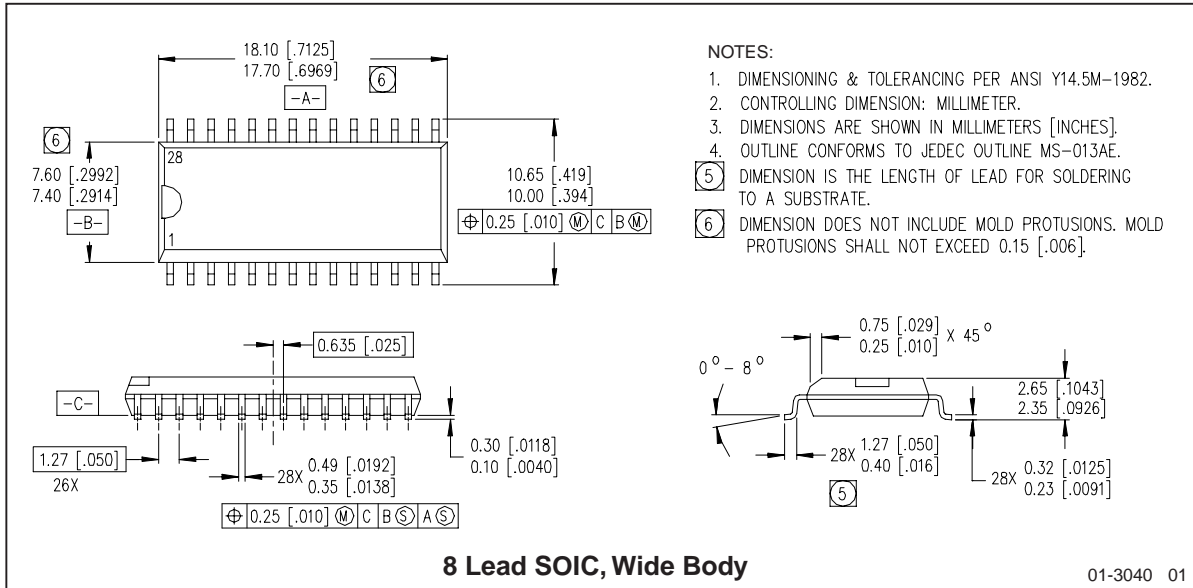
## Lead Assignments

<p><b>28 Lead DIP</b></p> <p><b>IR2133</b> <b>IR2135</b> <b>IR2233</b> <b>IR2235</b></p>	<p><b>44 Lead PLCC w/o 12 Leads</b></p> <p><b>IR2133J</b> <b>IR2135J</b> <b>IR2233J</b> <b>IR2235J</b></p>	<p><b>28 Lead SOIC (Wide Body)</b></p> <p><b>IR2133S</b> <b>IR2135S</b> <b>IR2233S</b> <b>IR2235S</b></p>
<b>Part Number</b>		

## Package Dimensions



# IR2133/IR2135/IR2233/IR2235 (J)(S)



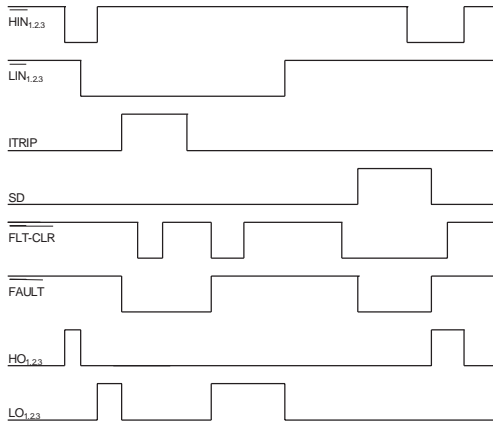


Figure 1. Input/Output Timing Diagram

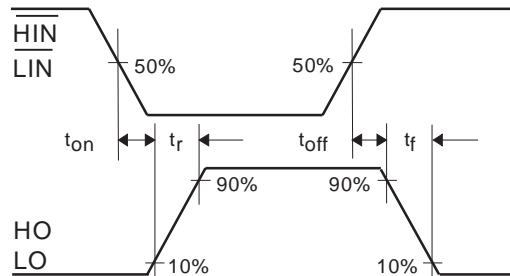


Figure 2. Switching Time Waveform Definitions

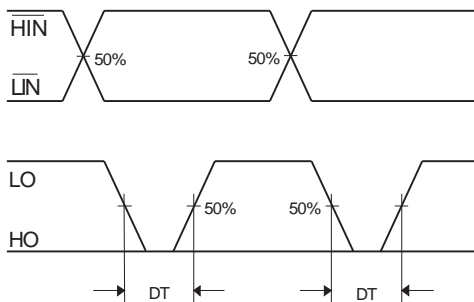


Figure 3. Deadtime Waveform Definitions

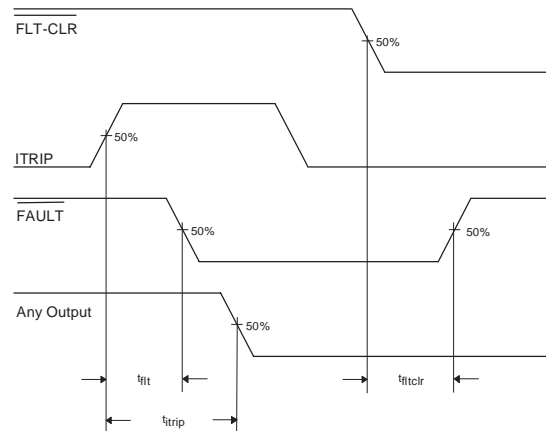


Figure 4. Overcurrent Shutdown Waveform

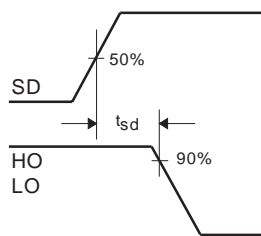


Figure 5. Shutdown Waveform Definitions



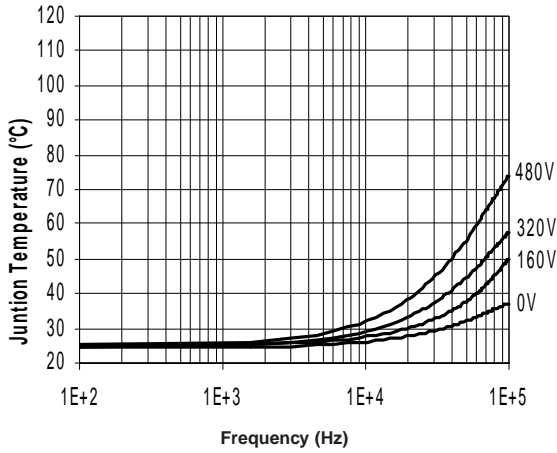


Figure 7. IR2133J Junction Temperature vs Frequency Driving (IRGPC20KD2) Rgate = 5.1Ω @ Vcc = 15V

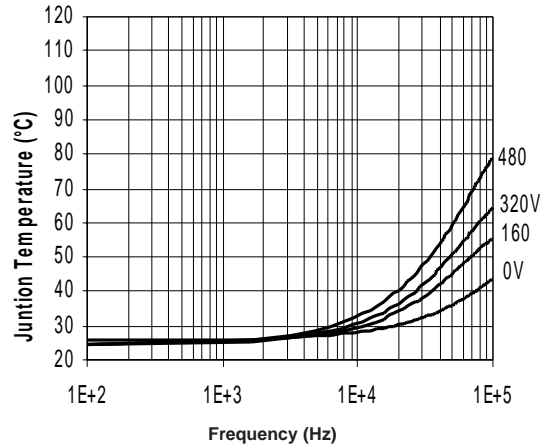


Figure 8. IR2133J Junction Temperature vs Frequency Driving (IRGPC30KD2) Rgate = 5.1Ω @ Vcc = 15V

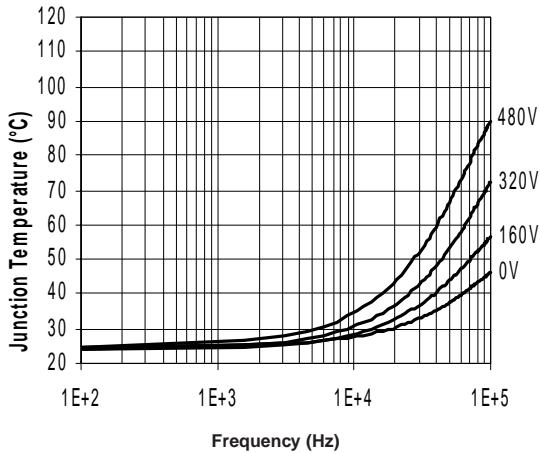


Figure 9. IR2133J Junction Temperature vs Frequency Driving (IRGPC40KD2) Rgate = 5.1Ω @ Vcc = 15V

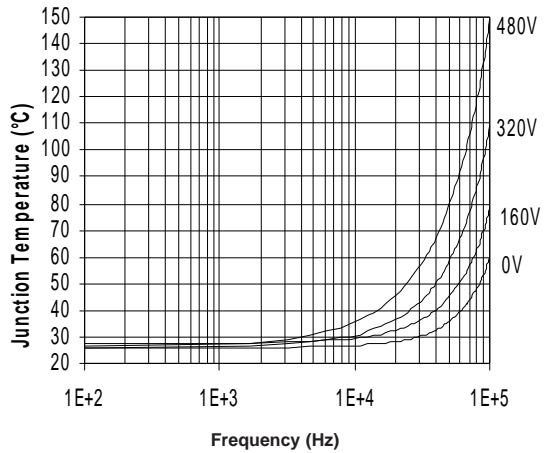


Figure 10. IR2133J Junction Temperature vs Frequency Driving (IRGPC50KD2) Rgate = 5.1Ω @ Vcc = 15V

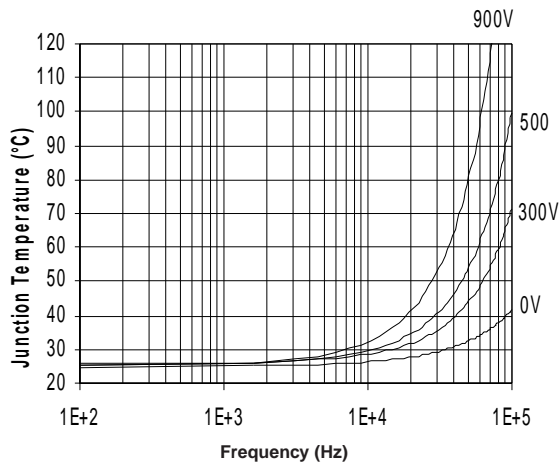


Figure 11. IR2233J Junction Temperature vs Frequency Driving (IRG4PH30KD) Rgate = 20Ω @ Vcc = 15V

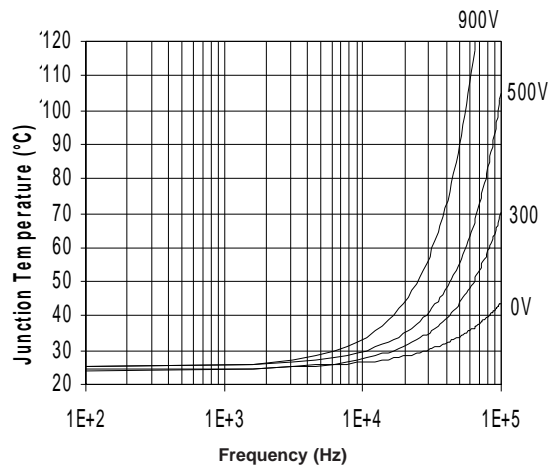


Figure 12. IR2233J Junction Temperature vs Frequency Driving (IRG4PH40KD) Rgate = 15Ω @ Vcc = 15V

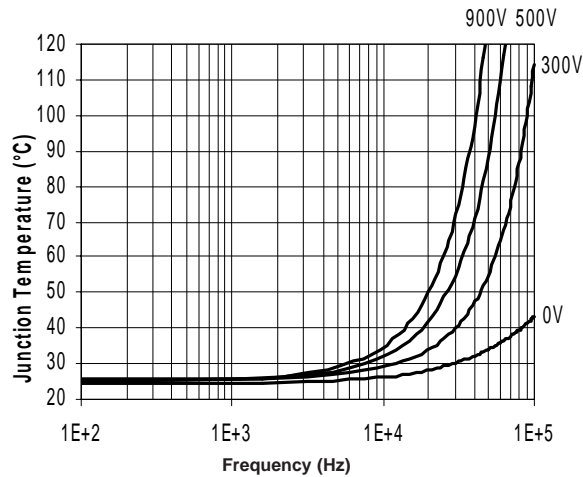


Figure 13. IR2233J Junction Temperature vs Frequency Driving (IRG4PH50KD) Rgate = 10Ω @ Vcc = 15V

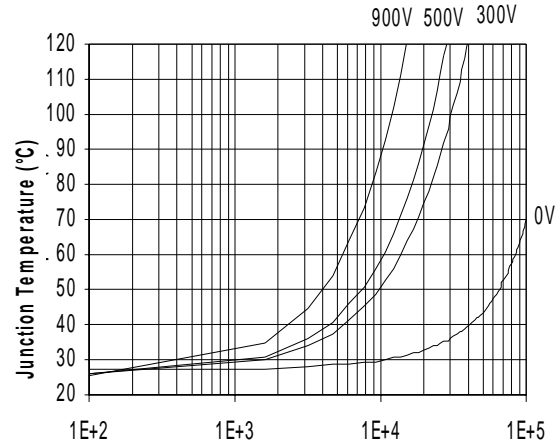


Figure 14. IR2133J Junction Temperature vs Frequency Driving (IRG4ZH71KD) Rgate = 5Ω @ Vcc = 15V